

P54/74FCT374T/AT/CT—P54/74FCT534T/AT/CT P54/74FCT564T/AT/CT—P54/74FCT574T/AT/CT OCTAL D FLIP-FLOPS WITH 3-STATE OUTPUTS

FEATURES

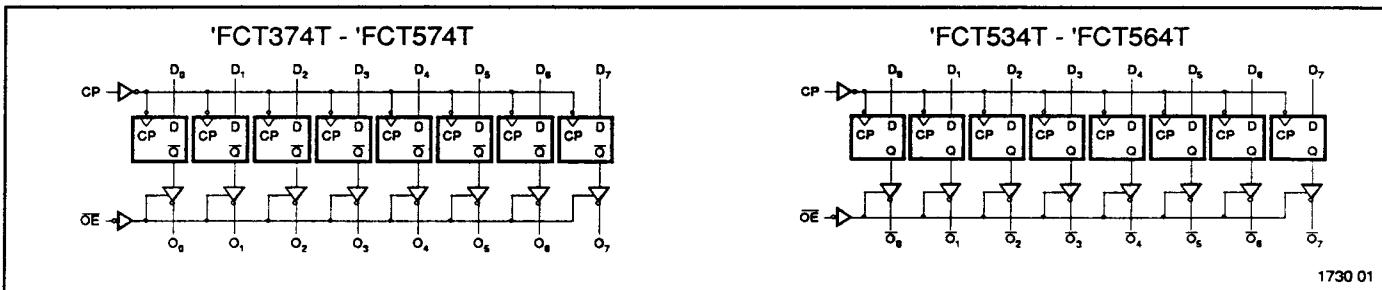
- Function, Pinout and Drive Compatible with the FCT and F Logic
- FCT-C speed at 5.2ns max. (Com'l)
FCT-A speed at 6.5ns max. (Com'l)
- Reduced V_{OH} (typically = 3.3V) versions of Equivalent FCT functions
- Edge-rate Control Circuitry for Significantly Improved Noise Characteristics
- ESD protection exceeds 2000V
- Power-off disable feature
- Matched Rise and Fall times
- Fully Compatible with TTL Input and Output Logic Levels
- 64 mA Sink Current (Com'l), 32 mA (MII)
15 mA Source Current (Com'l), 12 mA (MII)
- Edge Triggered D Type Inputs
- 250 MHz Typical Toggle Rate
- Buffered Positive Edge Triggered Clock
- Manufactured In 0.7 micron PACE Technology™

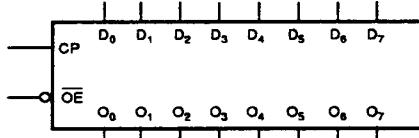
DESCRIPTION

The 'FCT374T, 'FCT534T, 'FCT564T and 'FCT574T are high-speed low power octal D-type flip-flops featuring separate D-type inputs for each flip-flop. Both devices have 3-state outputs for bus oriented applications. A buffered clock (CP) and output enable (\overline{OE}) are common to all flip-flops. The 'FCT534T is the same as the 'FCT374T except that the outputs are inverted. The 'FCT574T is identical to 'FCT374T except that all the outputs are on one side of the package and inputs on the other side. The

'FCT564 is the same as the 'FCT574T except that the outputs are inverted. The eight flip-flops contained in the 'FCT374T, 'FCT534T, 'FCT564T and 'FCT574T will store the state of their individual D inputs that meet the setup and hold time requirements on the low-to-high clock (CP) transition. When \overline{OE} is LOW, the contents of the eight flip-flops are available at the outputs. When \overline{OE} is HIGH, the outputs will be in the high impedance state. The state of output enable does not affect the state of the flip-flops.

LOGIC DIAGRAMS

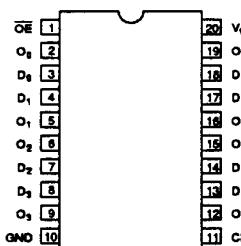


LOGIC SYMBOL'FCT374T - 'FCT534T* - 'FCT564T* -
FCT574T* \overline{O}_n for 'FCT534T and 'FCT564T

1730 02

PIN CONFIGURATIONS

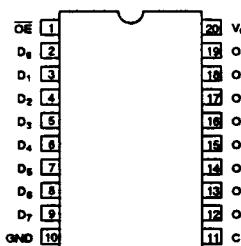
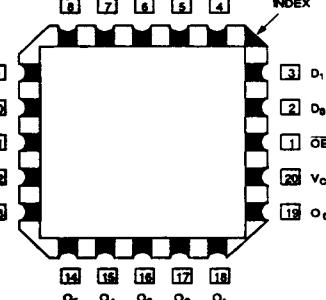
'FCT374T - 'FCT534T*

* \overline{O}_n for 'FCT534TDIP(D2, P2)
SOIC (S2)

LCC(L2)

1730 03

'FCT564T - 'FCT574T

* \overline{O}_n for 'FCT564TDIP(D2, P2)
SOIC (S2)

LCC(L2)

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ABSOLUTE MAXIMUM RATINGS^{1,2}

Symbol	Parameter	Value	Unit
T_{STG}	Storage Temperature	-65 to +150	°C
T_A	Ambient Temperature Under Bias	-65 to +135	°C
V_{CC}	V_{CC} Potential to Ground	-0.5 to +7.0	V
P_T	Power Dissipation	0.5	W

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Symbol	Parameter	Value	Unit
I_{OUTPUT}	Current Applied to Output	120	mA
V_{IN}	Input Voltage	-0.5 to +7.0	V
V_{OUT}	Voltage Applied to Output	-0.5 to +7.0	V

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Notes:

1. Operation beyond the limits set forth in the above table may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature range.

2. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V_{CC} or ground.

RECOMMENDED OPERATING CONDITIONS

Free Air Ambient Temperature	Min	Max
Military	-55°C	+125°C
Commercial	0°C	+70°C

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Supply Voltage (V_{CC})	Min	Max
Military	+4.5V	+5.5V
Commercial	+4.75V	+5.25V

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DC ELECTRICAL CHARACTERISTICS (Over recommended operating conditions)

Symbol	Parameter		Min	Typ ¹	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		
V_{IL}	Input LOW Voltage				0.8	V		
V_H	Hysteresis			0.2		V		All inputs
V_{IK}	Input Clamp Diode Voltage			-0.7	-1.2	V	MIN	$I_{IN} = -18mA$
V_{OH}	Output HIGH Voltage	Military Commercial	2.4 2.4	3.3 3.3		V	MIN V	$I_{OH} = -12mA$ $I_{OH} = -15mA$
V_{OL}	Output LOW Voltage	Military Commercial Commercial		0.3 0.3 0.3	0.5 0.5 0.5	V	MIN MIN MIN	$I_{OL} = 32mA$ $I_{OL} = 48mA$ $I_{OL} = 64mA$
I_I	Input HIGH Current				20	μA	MAX	$V_{IN} = V_{CC}$
I_{IH}	Input HIGH Current				5	μA	MAX	$V_{IN} = 2.7V$
I_{IL}	Input LOW Current				-5	μA	MAX	$V_{IN} = 0.5V$
I_{OZH}	Off State I_{out} HIGH-Level Output Current				10	μA	MAX	$V_{OUT} = 2.7V$
I_{OZL}	Off State I_{out} LOW-Level Output Current				-10	μA	MAX	$V_{OUT} = 0.5V$
I_{OS}	Output Short Circuit Current ²		-60	-120	-225	mA	MAX	$V_{OUT} = 0.0V$
I_{OFF}	Power-off Disable				100	μA	0V	$V_{OUT} = 4.5V$
C_{IN}	Input Capacitance ³			5	10	pF	MAX	All inputs
C_{OUT}	Output Capacitance ³			9	12	pF	MAX	All outputs
I_{cc}	Quiescent Power Supply Current			0.2	1.5	mA	MAX	$V_{IN} \leq 0.2V$, $V_{IN} \geq V_{CC} - 0.2V$

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Notes:

1. Typical limits are at $V_{CC} = 5.0V$, $T_A = +25^\circ C$ ambient.
 2. Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the

- chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{os} tests should be performed last.
 3. This parameter is guaranteed but not tested.

DC CHARACTERISTICS (Over recommended operating conditions unless otherwise specified.)

Symbol	Parameter	Typ ¹	Max	Units	Conditions
ΔI_{cc}	Quiescent Power Supply Current (TTL inputs)	0.5	2.0	mA	$V_{cc} = \text{MAX}$, $V_{in} = 3.4V^2$, $f_1 = 0$, Outputs Open
I_{cco}	Dynamic Power Supply Current ³	0.15	0.25	mA/mHz	$V_{cc} = \text{MAX}$, One Bit Toggling, 50% Duty Cycle, Outputs Open, $\overline{OE} = \text{GND}$, $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
I_c	Total Power Supply Current ⁵	1.7	4.0	mA	$V_{cc} = \text{MAX}$, $f_o = 10\text{MHz}$, 50% Duty Cycle, Outputs Open, One Bit Toggling at $f_1 = 5\text{MHz}$, $\overline{OE} = \text{GND}$, $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
		2.2	6.0	mA	$V_{cc} = \text{MAX}$, $f_o = 10\text{MHz}$, 50% Duty Cycle, Outputs Open, One Bit Toggling at $f_1 = 5\text{MHz}$, $\overline{OE} = \text{GND}$, $V_{in} = 3.4V$ or $V_{in} = \text{GND}$
		4.0	7.8 ⁴	mA	$V_{cc} = \text{MAX}$, $f_o = 10\text{MHz}$, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at $f_1 = 2.5\text{MHz}$, $\overline{OE} = \text{GND}$, $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
		6.2	16.8 ⁴	mA	$V_{cc} = \text{MAX}$, $f_o = 10\text{MHz}$, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at $f_1 = 2.5\text{MHz}$, $\overline{OE} = \text{GND}$, $V_{in} = 3.4V$ or $V_{in} = \text{GND}$

Notes:

1. Typical values are at $V_{cc} = 5.0V$, +25°C ambient and maximum loading.
2. Per TTL driven input ($V_{in} = 3.4V$); all other inputs at V_{cc} or GND.
3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
4. Values for these conditions are examples of the I_{cc} formula. These limits are guaranteed but not tested.
5. $I_c = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
 $I_c = I_{cc} + \Delta I_{cc} D_H N_T + I_{cco} (f_o/2 + f_1 N_i)$
 $I_{cc} = \text{Quiescent Current with CMOS input levels}$

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ΔI_{cc} = Power Supply Current for a TTL High Input
 $(V_{in} = 3.4V)$

D_H = Duty Cycle for TTL Inputs High

N_T = Number of TTL Inputs at D_H

I_{cco} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_o = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f_1 = Input Frequency

N_i = Number of Inputs at f_1

All currents are in millamps and all frequencies are in megahertz.

TRUTH TABLE

Inputs			Outputs 'FCT374T-'FCT574T		Outputs 'FCT534T-'FCT564T	
D_n	CP	\overline{OE}	O_n		\overline{O}_n	
H	—	L	H		L	
L	—	L	L		H	
X	X	H	Z		Z	

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H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

— = LOW-to-HIGH clock transition

Z = HIGH Impedance

AC CHARACTERISTICS

Sym.	Parameter	'FCT374T-'FCT534T 'FCT564T-'FCT574T				'FCT374AT-'FCT534AT 'FCT564AT-'FCT574AT				'FCT374CT-'FCT534CT 'FCT564CT-'FCT574CT				Units	Fig. No.		
		MIL		COM'L		MIL		COM'L		MIL		COM'L					
		Min. ¹	Max.	Min. ¹	Max.	Min. ¹	Max.	Min. ¹	Max.	Min. ¹	Max.	Min. ¹	Max.				
t_{PLH}	Prop. Delay Clock to Output	2.0	11.0	2.0	10.0	2.0	7.2	2.0	6.5	2.0	6.2	2.0	5.2	ns	1, 5		
t_{PZH}	Output Enable Time	1.5	14.0	1.5	12.5	1.5	7.5	1.5	6.5	1.5	6.2	1.5	5.5	ns	1,7,8		
t_{PHZ}	Output Disable Time	1.5	8.0	1.5	8.0	1.5	6.5	1.5	5.5	1.5	5.7	1.5	5.0	ns	1,7,8		

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Note:

1. AC Characteristics guaranteed with $C_L = 50\text{pF}$ as shown in Figure 1.

AC CHARACTERISTICS

Sym.	Parameter	'FCT374T-'FCT534T 'FCT564T-'FCT574T				'FCT374AT-'FCT534AT 'FCT564AT-'FCT574AT				'FCT374CT-'FCT534CT 'FCT564CT-'FCT574CT				Units	Fig. No.		
		MIL		COM'L		MIL		COM'L		MIL		COM'L					
		Min. ¹	Max.	Min. ¹	Max.	Min. ¹	Max.	Min. ¹	Max.	Min. ¹	Max.	Min. ¹	Max.				
$t_s(H)$	Setup Time, High or Low D_n to CP	2.0	—	2.0	—	2.0	—	2.0	—	2.0	—	2.0	—	ns	4		
$t_n(H)$	Hold Time, High or Low D_n to CP	1.5	—	1.5	—	1.5	—	1.5	—	1.5	—	1.5	—	ns			
$t_w(H)$	Clk Pulse Width ² High or Low	7.0	—	7.0	—	6.0	—	5.0	—	6.0	—	5.0	—	ns	5		

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Notes:

1. Minimum limits are guaranteed but not tested on Propagation Delays.
2. With one data channel toggling, $t_w(L) = t_w(H) = 4.0\text{ns}$ and $t_s = t_n = 1.0\text{ns}$.

ORDERING INFORMATION

PxxFCT Temp. Class	xxxx Device type	X Package	X Processing											
				Blank										
				M										
				B										
				P										
				D										
				SO										
				L										
					374T/534T/564T/574T									
					374AT/534AT/564AT/574AT									
					374CT/534CT/564CT/574CT									
						OCTAL D Flip-Flop								
						Fast OCTAL D Flip-Flop								
						Ultra Fast OCTAL D Flip-Flop								
							Commercial							
							Military							
					74									
					54									

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